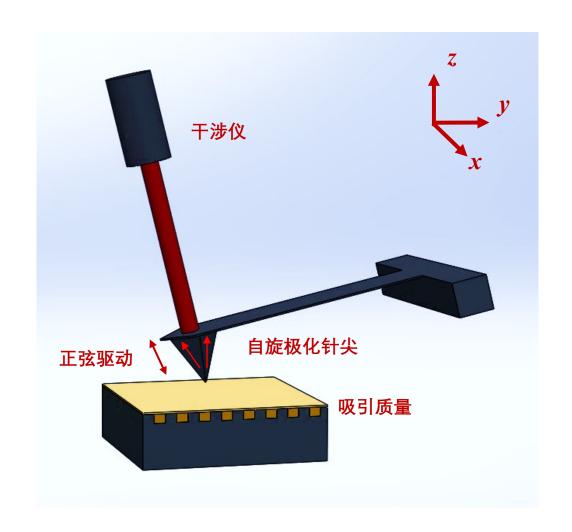


# 扫描探针显微技术

天眷1801 欧阳泽 2020.10.17

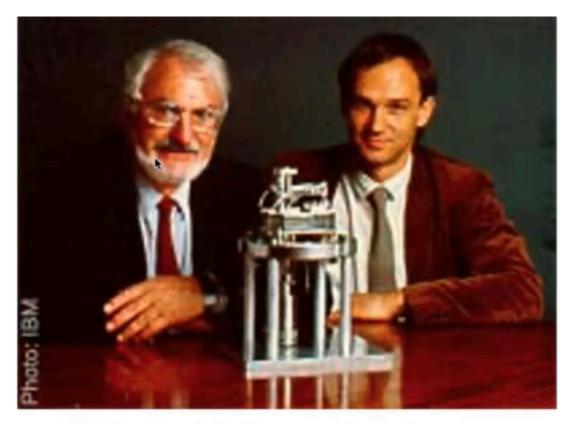


- 扫描隧道显微镜发展历程
- 精密位移控制
- 微弱信号测量
- 扫描探针显微镜应用



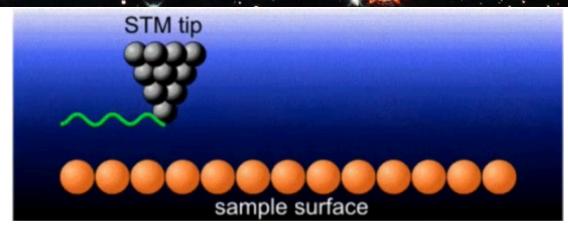
#### STM(Scanning Tunnel Microscope,扫描隧道显微镜)

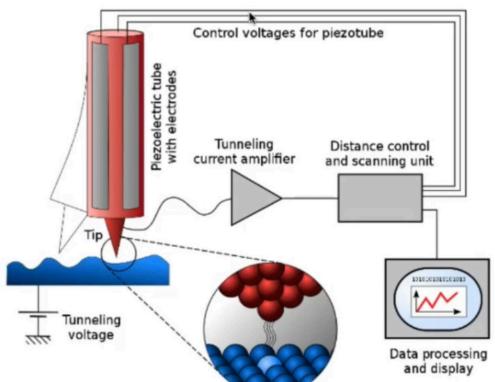
The invention of the scanning tunneling microscope(STM) by G. Binnig and H. Rohrer in 1981.(Nobel Prize in physics in 1986)



IBM's Zurich Research Laboratory

## STM(Scanning Tunnel Microscope,扫描隧道显微镜)





- 隧道电流:nA, pA
- 工作间距:nm
- 原子分辨:

Z: 0.01 nm

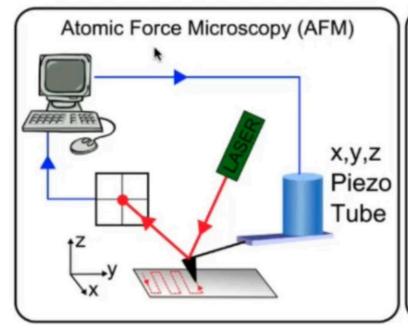
XY: 0.1 nm

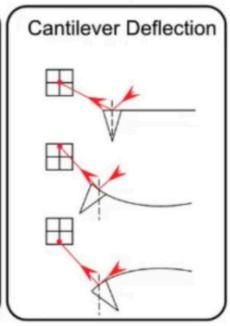
#### 需要:

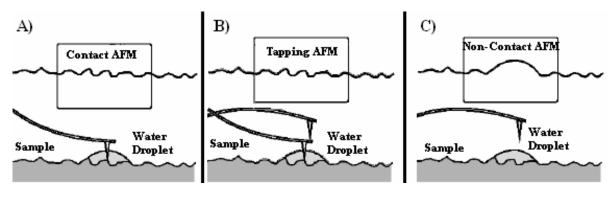
- 精密位移控制
- 微弱信号测量
- 环境(低温、低振动、真空)
- 系统控制

#### AFM(Atomic Force Microscope, 原子力显微镜)

The first and most important extension of the STM was the scanning force microscope(SFM) or atomic force microscope(AFM), invented in 1986 by Binnig, Quate and Gerber.







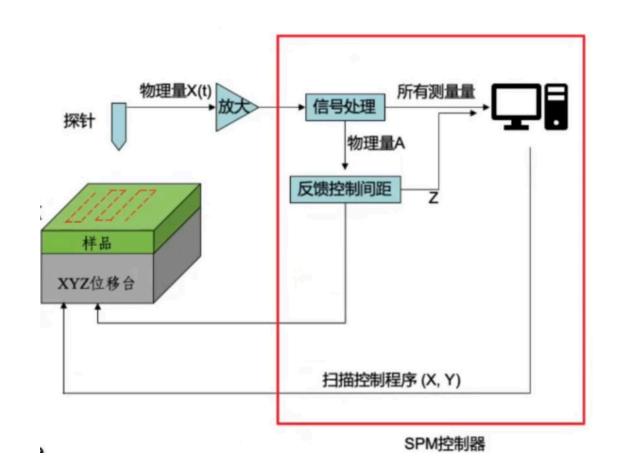
#### Scanning Probe Microscope Family(SPM)

- STM: 金属针尖, 隧道电流
- AFM:悬臂梁针尖,悬臂梁位移
- MFM(磁力显微镜):AFM扫出表面形貌;

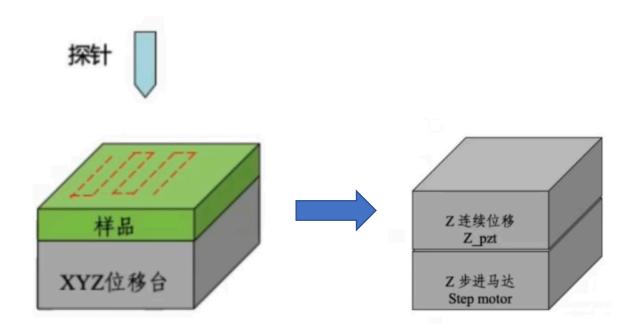
设置间距重扫

• SNOM(扫描近场光学显微镜):光纤,光信号

scanning squid microscope scanning capacitance microscope



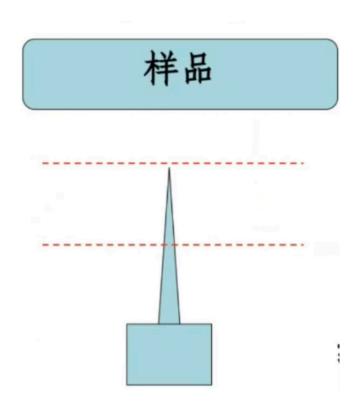
#### 精密位移控制

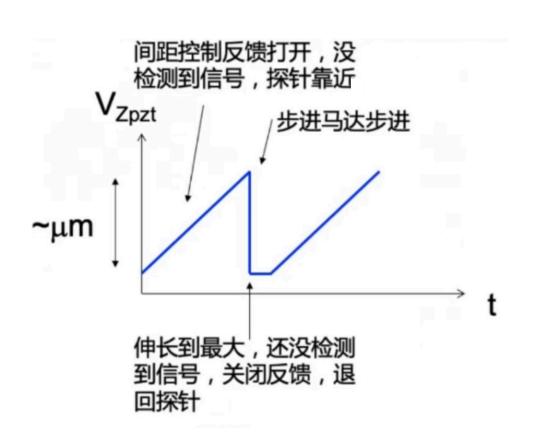


#### 精密位移的实现依赖于:

- 压电陶瓷的压电特性——连续位移
- 进针程序、步进马达——离散位移
- 反馈控制 (PID反馈)

#### 精密位移控制(进针程序)





#### 精密位移控制(PID反馈)

$$u(t) = K_p \left[ e(t) + \frac{1}{T_i} \int_0^t e(\tau) d\tau + T_d \frac{de(t)}{dt} \right]$$

Laplace transform

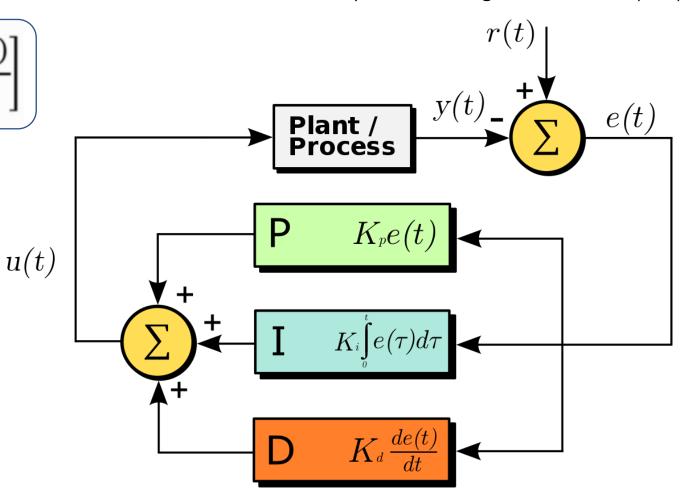
传递函数:

$$s = i\omega$$

$$G(s) = \frac{U(s)}{E(s)} = K_p \left[ 1 + \frac{1}{T_i s} + T_d s \right]$$

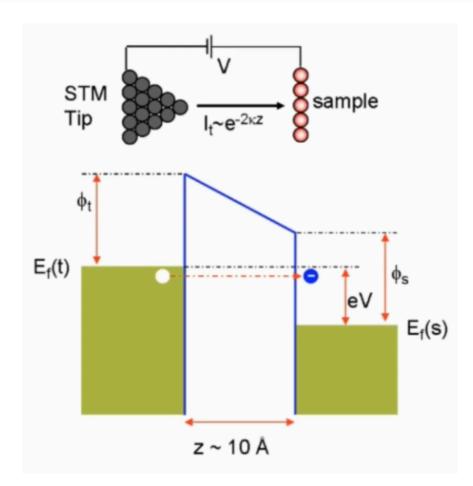
$$= K_p + K_i \frac{1}{s} + K_d s$$

比例-积分-微分反馈, Proportion-Integral-Derivative(PID)



#### 微弱信号测量

$$I = \int_{0}^{eV} \rho_t(E) \rho_s(E - eV) [f(E) - f(E - eV)] T(E, eV) dE$$



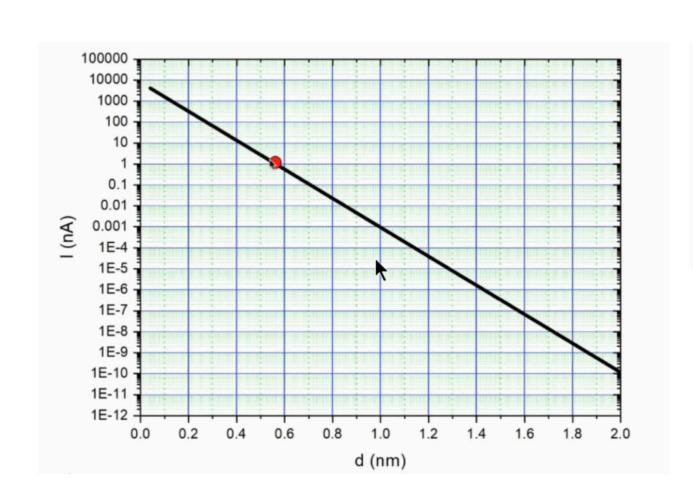
$$I \propto e^{-2\kappa z}$$

$$\frac{\mathrm{d}\boldsymbol{I}}{\mathrm{d}\boldsymbol{V}} \propto \rho_s(\vec{r}, \boldsymbol{eV})$$

#### 局域态密度测量

$$k \approx \frac{\sqrt{2m_e\phi_0}}{\hbar}$$
 Au:  $\phi_0 = 4.83 \ eV$ 

#### 微弱信号测量

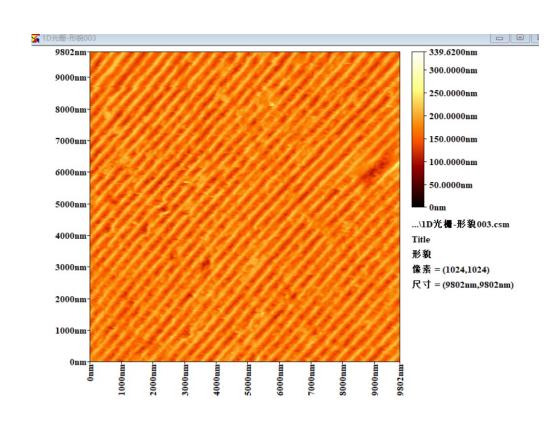


• 电流放大器:

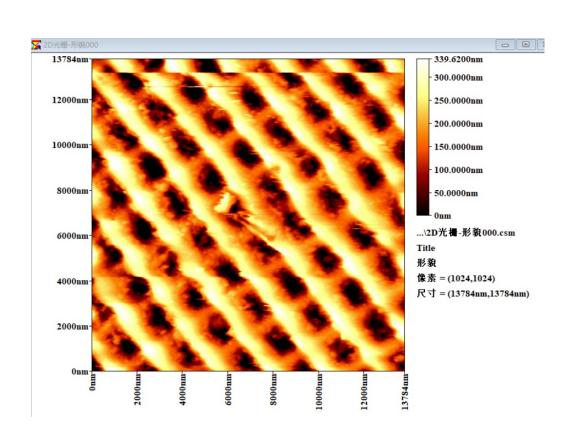


• 双绞线、同轴线(回路中的感应电流)

### 扫描探针显微镜的应用:表面形貌

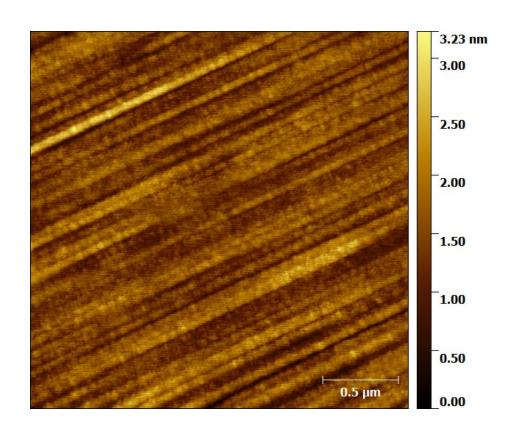


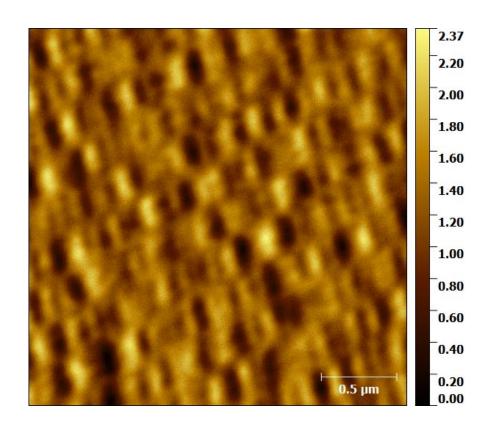
一维光栅, 周期尺寸为190nm



二维光栅, 周期尺寸1.8um

# 扫描探针显微镜的应用:表面形貌

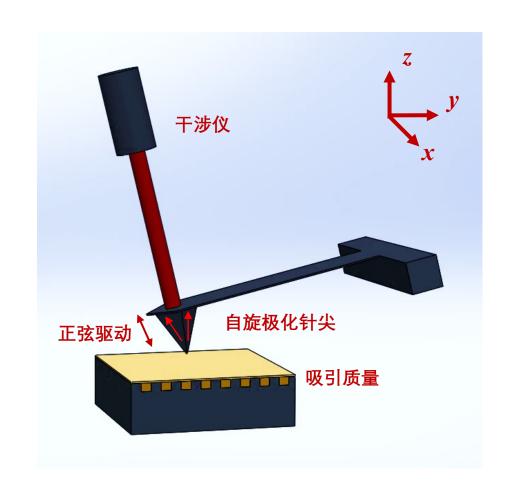


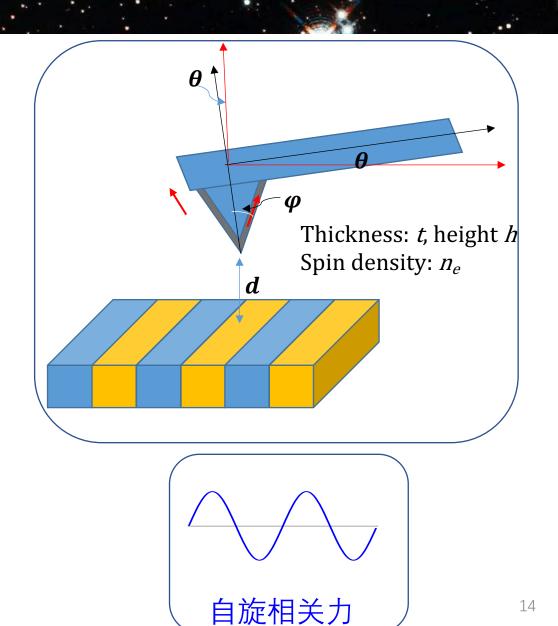


磁盘形貌图

磁盘磁畴图

$$V_{12+13} = A f_v \frac{\hbar}{8\pi} \int n_a dV_a \int n_e dV_e \frac{v}{v} \cos \varphi \left(\frac{1}{r}\right) e^{-\frac{r}{\lambda}}$$





# 谢谢!